

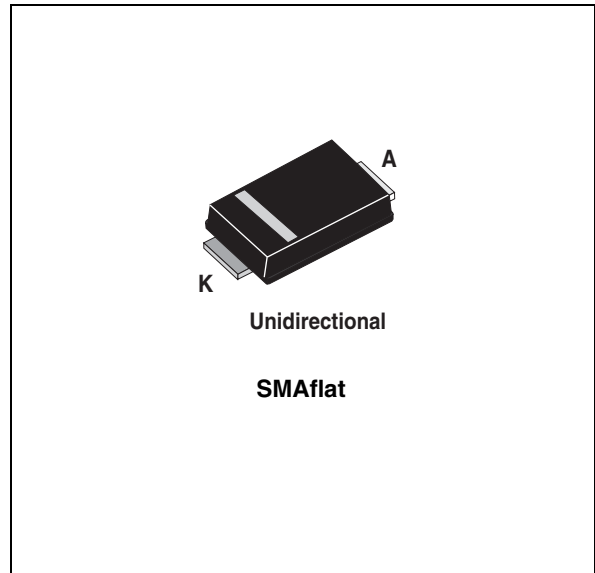
High junction temperature Transil™

Features

- ECOPACK2® halogen-free component
- Peak pulse power:
 - 400 W (10/1000 μ s)
 - 3 kW (8/20 μ s)
- Stand off voltage: 5 V
- Unidirectional type
- Low clamping voltage versus standard series
- Low leakage current, 10 μ A at 25 °C
- Operating T_j max: 175 °C
- JEDEC registered package outline

Complies with the following standards

- IEC 61000-4-2 level 4:
 - 15 kV (air discharge)
 - 8 kV (contact discharge)
- MIL STD 883G-Method 3015-7: class3B
 - 25 kV (human body model)



Description

The SMA4F Transil series has been designed to protect sensitive equipment against electrostatic discharges according to IEC 61000-4-2, MIL STD 883 Method 3015, and electrical over stress such as IEC 61000-4-4 and 5. They are generally for surges below 400 W 10/1000 μ s.

This planar technology makes it compatible with high-end equipment and SMPS where low leakage current and high junction temperature are required to provide reliability and stability over time. Their low clamping voltages provides a better safety margin to protect sensitive circuits with extended life time expectancy.

Packaged in SMAflat non exposed pad, this minimizes PCB space consumption (footprint in accordance with IPC 7531 standard).

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1 Characteristics

Table 1. Absolute ratings ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter		Value	Unit
P_{PP}	Peak pulse power dissipation ⁽¹⁾	$T_j \text{ initial} = T_{amb}$	400	W
I_{FSM}	Non repetitive surge peak forward current for unidirectional types	$t_p = 10\text{ ms}$ $T_j \text{ initial} = T_{amb}$	40	A
T_{stg}	Storage temperature range		-65 to +175	$^{\circ}\text{C}$
T_j	Operating junction temperature range		-55 to +175	$^{\circ}\text{C}$
T_L	Maximum lead temperature for soldering during 10 s		260	$^{\circ}\text{C}$

1. For a surge greater than the maximum values, the diode will fail in short-circuit.

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-l)}$	Junction to leads	20	$^{\circ}\text{C/W}$

Table 3. Electrical characteristics - definitions ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

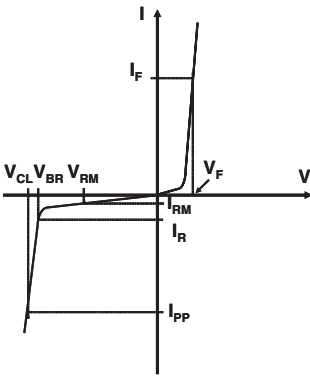
Symbol	Parameter	
V_{RM}	Stand-off voltage	
V_{BR}	Breakdown voltage	
V_{CL}	Clamping voltage	
I_{RM}	Leakage current @ V_{RM}	
I_{PP}	Peak pulse current	
α_T	Voltage temperature coefficient	
V_F	Forward voltage drop	
R_D	Dynamic resistance	

Table 4. Electrical characteristics - values ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

Type	$I_{RM} \text{ max@}V_{RM}$			$V_{BR} \text{ @}I_R^{(1)}$				$V_{CL} \text{ @}I_{PP}$ 10/1000 μs		$R_D^{(2)}$ 10/1000 μs	$V_{CL} \text{ @}I_{PP}$ 8/20 μs		$R_D^{(2)}$ 8/20 μs	$\alpha T^{(3)}$
	25 $^{\circ}\text{C}$	85 $^{\circ}\text{C}$		min	typ	max		max			max			max
	$\mu\text{A (Max)}$		V	V			mA	V	A	Ω	V	A	Ω	10-4/ $^{\circ}\text{C}$
SMA4F5.0A	10	50	5.0	6.40	6.74	7.10	10	9.2	43.5	0.048	13.4	174	0.036	5.7

1. Pulse test: $t_p < 50\text{ms}$.
2. To calculate maximum clamping voltage at other surge currents, use the following formula
 $V_{CLmax} = R_D \times I_{PP} + V_{BRmax}$
3. To calculate V_{BR} versus junction temperature, use the following formula:
 $V_{BR} \text{ @ } T_j = V_{BR} \text{ @ } 25\text{ }^{\circ}\text{C} \times (1 + \alpha T \times (T_j - 25))$

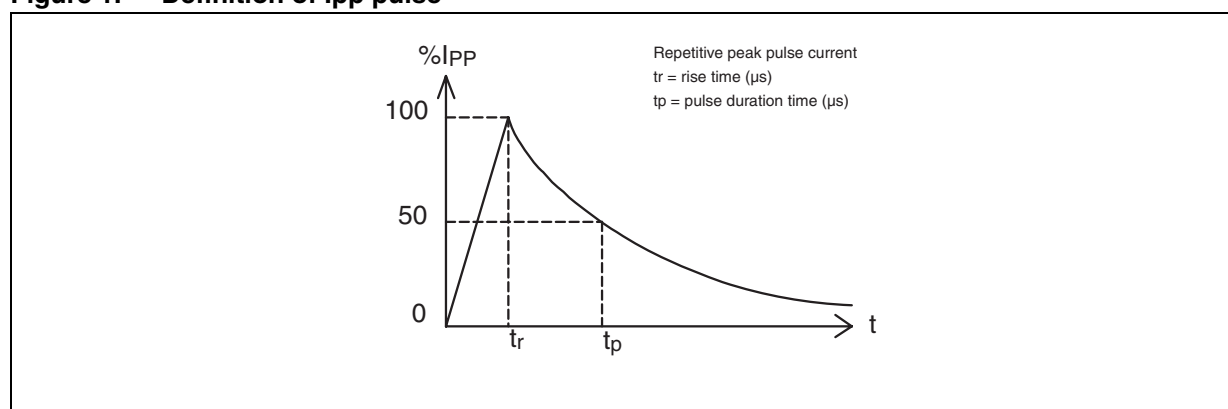
Figure 1. Definition of I_{PP} pulse

Figure 2. Relative peak power dissipation versus initial junction temperature

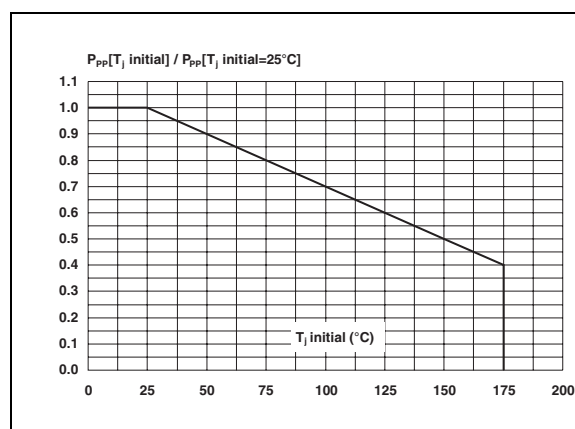
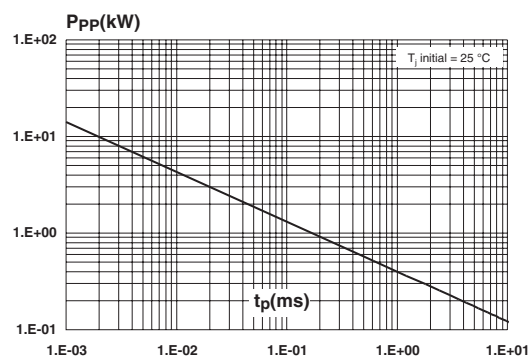
Figure 3. Peak pulse power versus exponential pulse duration ($T_j \text{ initial} = 25\text{ }^{\circ}\text{C}$)

Figure 4. Clamping voltage versus peak pulse current (exponential waveform, maximum values)

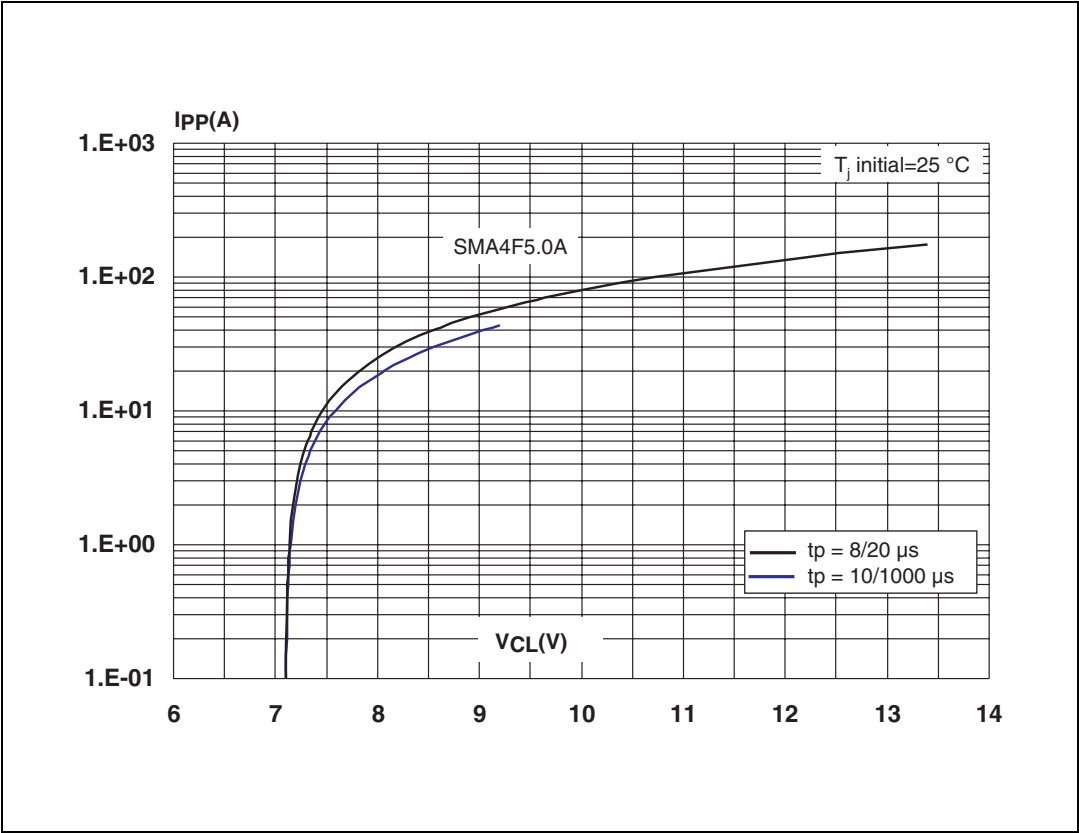


Figure 5. Junction capacitance versus reverse applied voltage (typical values)

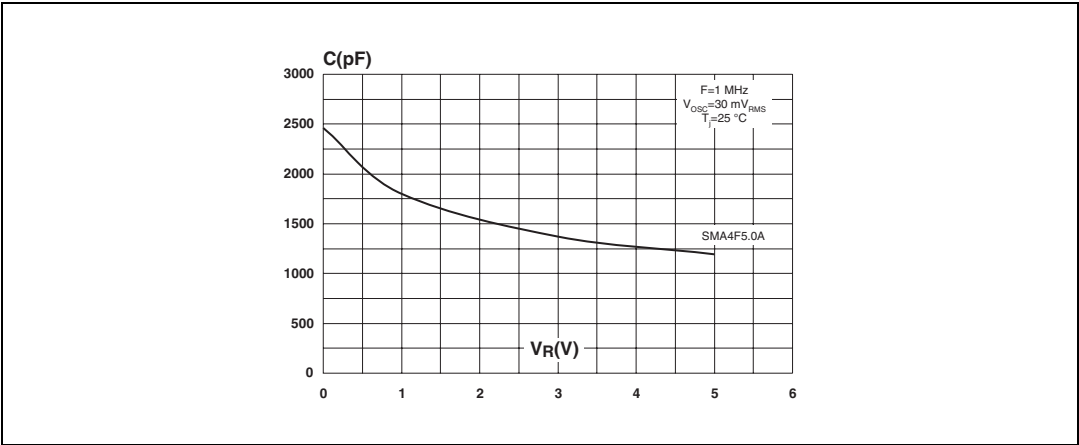


Figure 6. Peak forward voltage drop versus peak forward current (typical values)

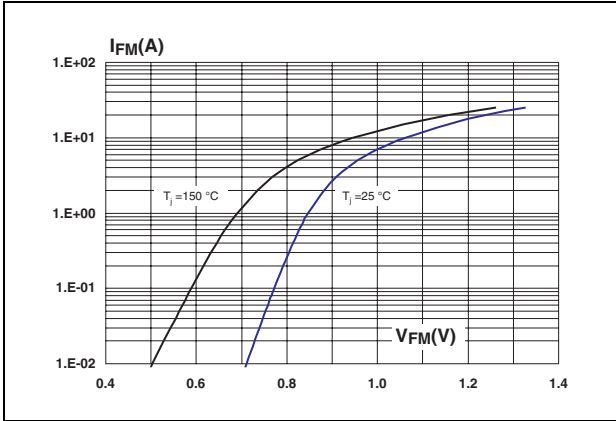


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration (printed circuit board FR4, $S_{Cu} = 1\text{ cm}^2$)

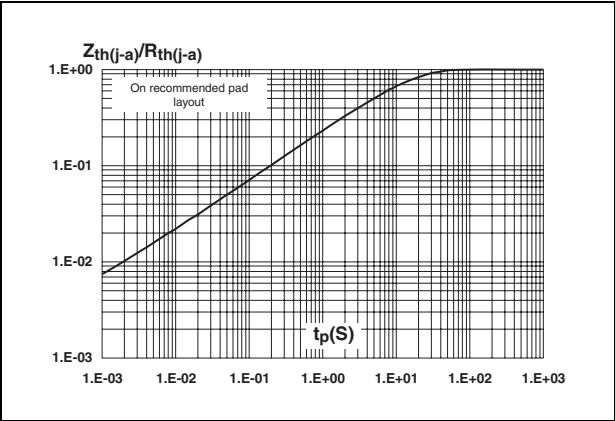


Figure 8. Thermal resistance junction to ambient versus copper surface under each lead (printed circuit board FR4, copper thickness = $35\text{ }\mu\text{m}$)

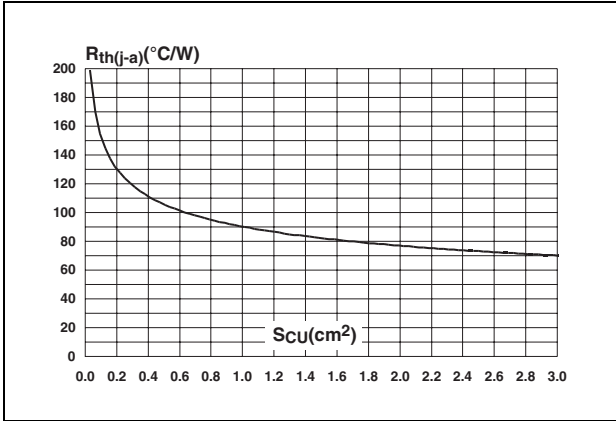
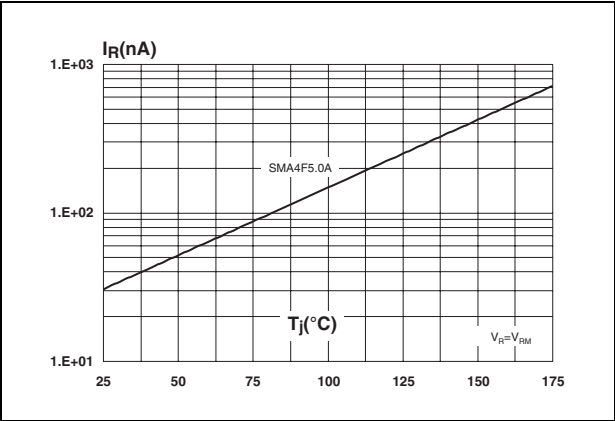
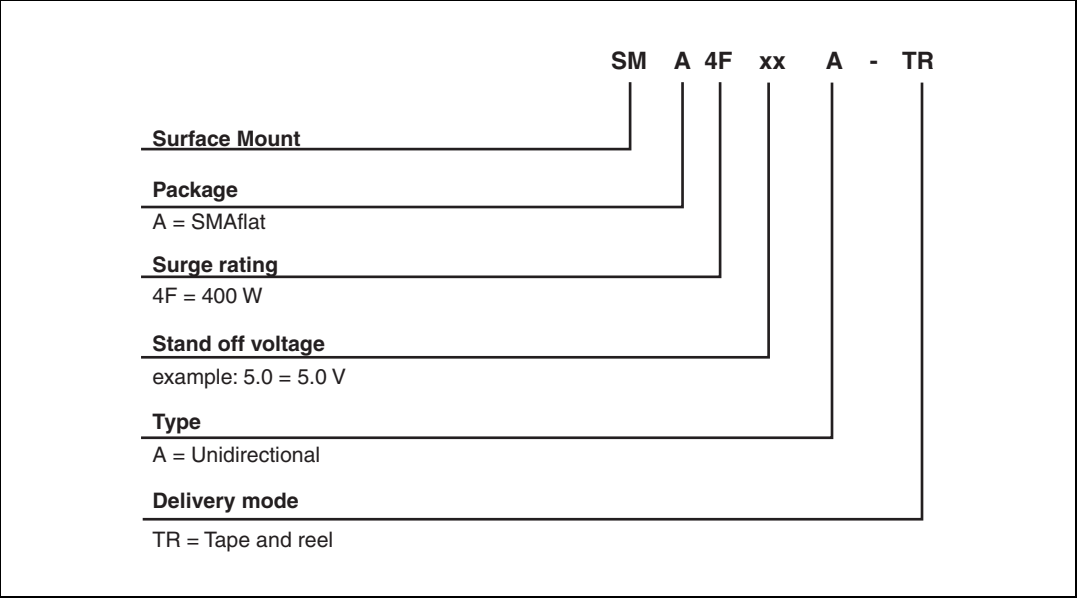


Figure 9. Leakage current versus junction temperature (typical values)



2 Ordering information scheme

Figure 10. Ordering information scheme



4 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
SMA4F5.0A-TR	SAE	SMAflat	0.035 g	10 000	Tape and reel

5 Revision history

Table 7. Document revision history

Date	Revision	Changes
04-Sep-2008	1	First issue.

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